

Surface-Mount Glass Passivated Rectifier


SMA (DO-214AC)

Cathode  Anode

ADDITIONAL RESOURCES


[3D Models](#)

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	1.0 A
V_{RRM}	50 V, 100 V, 200 V, 400 V, 600 V, 800 V, 1000 V
I_{FSM}	40 A, 30 A
E_{AS}	5 mJ
I_R	1.0 μ A, 5.0 μ A
V_F	1.1 V
T_J max.	150 °C
Package	SMA (DO-214AC)
Circuit configuration	Single

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated pellet chip junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 or P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive, and telecommunication.

MECHANICAL DATA

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, commercial grade

Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified
Base P/NHM3_X - halogen-free, RoHS-compliant and AEC-Q101 qualified

("X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3, M3, HE3, and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	S1A	S1B	S1D	S1G	S1J	S1K	S1M	UNIT
Device marking code		SA	SB	SD	SG	SJ	SK	SM	
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	1.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	40					30		A
Non-repetitive peak reverse avalanche energy at 25 °C, I _{AS} = 1 A, L = 10 mH	E _{AS}	5							mJ
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150							°C